NSN 5961-01-064-4870



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-064-4870 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.340 inches Overall Diameter: 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 12.0 emitter to base voltage, dc and 150.0 collector to base voltage, dc **Current Rating Per Characteristic:** 5.00 amperes source cutoff current and 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 1 case and 3 pin **Specification Data:** 81349-mil-s-19500/472/el/ government specification Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: